Monolithic Digital IC



NO.783C

LB1272

6-Unit, Darlington Transistor Array

The circuit configuration of this IC is a 6-unit Darlington transistor array consisting of NPN transistors and is ideally suited for use in printer hammer driving, lamp or relay driving applications. With the built-in protective diodes against negative inputs, this IC offers advantages to the driver circuit design of electronic calculator with printer and cash resister, etc. which also use display tubes.

Features

- · Ideally suited for 18-digit printer because of built-in 6 units.
- · With built-in protective diodes against negative inputs.
- Ideally suited for printer mechanism with load current 85 mA.

Absolute Maximum Ratings at Ta=25°C

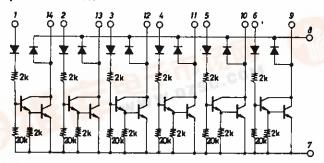
Output Supply Voltage	Vout		-0.3 to +22	V
Input Supply Voltage	V_{IN}		-40 to +12	V
Pin 8 Supply Voltage	Vcc		-0.3 to +20	V
Output Flow-in Current	IOUT	Per unit	100	mΑ
Instantaneous Output	IOP	Per unit, duty=10%	150	mΑ
Flow-in Current		Pulse width<20ms		
Spark Killer Diode Forward Current	IF(S)	"	150	mΑ
GND Pin Flow-out Current	IGP	H	-900 to 0	mΑ
Pin 8 Instantaneous Flow-out Current	ICCP	"	-900 to 0	mA
Pin 8 Flow-out Current	Icc		-600 to 0	mΑ
Allowable Power Dissipation	P _d max		770	mA
Operating Temperature	Topr		-20 to +80	°C
Storage Temperature	T _{stg}		-40 to +125	°C

Allowable Operating Conditions at T₂ = 25°C

nowabie operating contains	iis at ia — 25 C			unit
Output Supply Voltage	Vout		22	V max
Input High Level Voltage	VIH.	Output pin current=100mA	3 to 12	V
Input Low Level Voltage	VIL	Output pin current=100µA	-35 to +1	V
Load Inductance	LL	Using protective diode	100	mH max

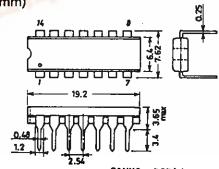
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Equivalent Circuit



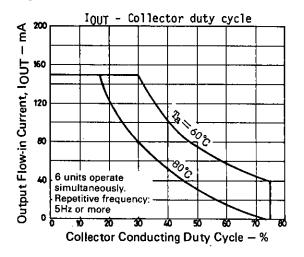
Unit (resistance: Ω)

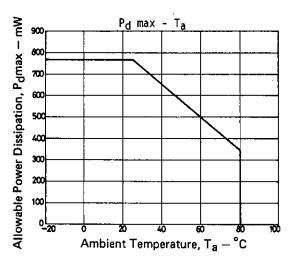




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Operating Characteristics at T _a =25°C			min	typ	max	unit
Output Voltage	VOUT(1)	VIN=3V, IOUT=150mA		,,	1.7	V
	VOUT(2)	VIN=3V, IOUT=100mA			1.4	V
Output Sustain Voltage	VOUT(s)	V _{IN} =open, I _{OUT} =150mA Applied time < 10μs	22			V
Output Leakage Current	loff	V _{IN} =1V, V _{out} =22V			100	μΑ
Input Current	IIN	V _{IN} =3V		,	1	mΑ
Output Current	IOUT	I _{IN} =0.3mA, V _{OUT} =1.4V	100			mΑ
Input Leakage Current	l _{leak}	V _{IN} =-35V	-10			μΑ
Spark Killer Diode Leakage Current	leak(s)	V _{OUT} =0V, Pin8=20V			30	μΑ
Spark Killer Diode Foward Voltage	VF(S)	IF(3)=150mA			1.7	. V





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